# NSN 5961-01-361-2299

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-361-2299

1	Camfiannatian	
internai	Configuration:	
ca.	Oomingaration.	

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-205af

#### **Semiconductor Material:**

Silicon

### Voltage Rating In Volts Per Characteristic:

400.0 drain to source voltage and 400.0 drain to gate voltage and 400.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

# **Test Data Document:**

81349-mil-s-19500h specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Specification Data:**

81349-mil-s-19500/556b government specification

Shelf Life:

N/a

**Unit Of Measure:** 

--

### **Demilitarization:**

Yes - demil/mli

Fiig:

A110a0